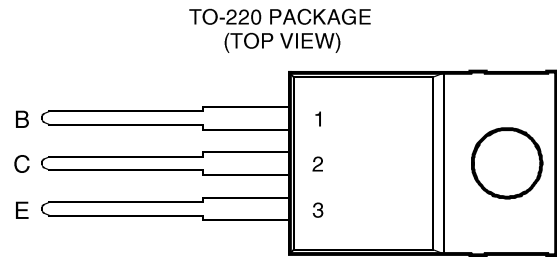




## TIP115, TIP116, TIP117 PNP SILICON POWER DARLINGTONS

- Designed for Complementary Use with TIP110, TIP111 and TIP112
- 50 W at 25°C Case Temperature
- 4 A Continuous Collector Current
- Minimum  $h_{FE}$  of 500 at 4 V, 2 A



Pin 2 is in electrical contact with the mounting base.

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

| RATING                                                                             |        | SYMBOL              | VALUE       | UNIT |
|------------------------------------------------------------------------------------|--------|---------------------|-------------|------|
| Collector-base voltage ( $I_E = 0$ )                                               | TIP115 | $V_{CBO}$           | -60         | V    |
|                                                                                    | TIP116 |                     | -80         |      |
|                                                                                    | TIP117 |                     | -100        |      |
| Collector-emitter voltage ( $I_B = 0$ )                                            | TIP115 | $V_{CEO}$           | -60         | V    |
|                                                                                    | TIP116 |                     | -80         |      |
|                                                                                    | TIP117 |                     | -100        |      |
| Emitter-base voltage                                                               |        | $V_{EBO}$           | -5          | V    |
| Continuous collector current                                                       |        | $I_C$               | -4          | A    |
| Peak collector current (see Note 1)                                                |        | $I_{CM}$            | -6          | A    |
| Continuous base current                                                            |        | $I_B$               | -50         | mA   |
| Continuous device dissipation at (or below) 25°C case temperature (see Note 2)     |        | $P_{tot}$           | 50          | W    |
| Continuous device dissipation at (or below) 25°C free air temperature (see Note 3) |        | $P_{tot}$           | 2           | W    |
| Unclamped inductive load energy (see Note 4)                                       |        | $\frac{1}{2}LI_C^2$ | 25          | mJ   |
| Operating junction temperature range                                               |        | $T_j$               | -65 to +150 | °C   |
| Storage temperature range                                                          |        | $T_{stg}$           | -65 to +150 | °C   |
| Lead temperature 3.2 mm from case for 10 seconds                                   |        | $T_L$               | 260         | °C   |

NOTES: 1. This value applies for  $t_p \leq 0.3$  ms, duty cycle  $\leq 10\%$ .  
2. Derate linearly to 150°C case temperature at the rate of 0.4 W/°C.  
3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.  
4. This rating is based on the capability of the transistor to operate safely in a circuit of:  $L = 20$  mH,  $I_{B(on)} = -5$  mA,  $R_{BE} = 100 \Omega$ ,  $V_{BE(off)} = 0$ ,  $R_S = 0.1 \Omega$ ,  $V_{CC} = -20$  V.

# TIP115, TIP116, TIP117

## PNP SILICON POWER DARLINGTONS

### electrical characteristics at 25°C case temperature

| PARAMETER     |                                      | TEST CONDITIONS                                                                   |                                              |                            | MIN                | TYP | MAX            | UNIT |
|---------------|--------------------------------------|-----------------------------------------------------------------------------------|----------------------------------------------|----------------------------|--------------------|-----|----------------|------|
| $V_{(BR)CEO}$ | Collector-emitter breakdown voltage  | $I_C = -30 \text{ mA}$<br>(see Note 5)                                            | $I_B = 0$                                    | TIP115<br>TIP116<br>TIP117 | -60<br>-80<br>-100 |     |                | V    |
| $I_{CEO}$     | Collector-emitter cut-off current    | $V_{CE} = -30 \text{ V}$<br>$V_{CE} = -40 \text{ V}$<br>$V_{CE} = -50 \text{ V}$  | $I_B = 0$<br>$I_B = 0$<br>$I_B = 0$          | TIP115<br>TIP116<br>TIP117 |                    |     | -2<br>-2<br>-2 | mA   |
| $I_{CBO}$     | Collector cut-off current            | $V_{CB} = -60 \text{ V}$<br>$V_{CB} = -80 \text{ V}$<br>$V_{CB} = -100 \text{ V}$ | $I_E = 0$<br>$I_E = 0$<br>$I_E = 0$          | TIP115<br>TIP116<br>TIP117 |                    |     | -1<br>-1<br>-1 | mA   |
| $I_{EBO}$     | Emitter cut-off current              | $V_{EB} = -5 \text{ V}$                                                           | $I_C = 0$                                    |                            |                    |     | -2             | mA   |
| $h_{FE}$      | Forward current transfer ratio       | $V_{CE} = -4 \text{ V}$<br>$V_{CE} = -4 \text{ V}$                                | $I_C = -1 \text{ A}$<br>$I_C = -2 \text{ A}$ | (see Notes 5 and 6)        | 1000<br>500        |     |                |      |
| $V_{CE(sat)}$ | Collector-emitter saturation voltage | $I_B = -8 \text{ mA}$                                                             | $I_C = -2 \text{ A}$                         | (see Notes 5 and 6)        |                    |     | -2.5           | V    |
| $V_{BE}$      | Base-emitter voltage                 | $V_{CE} = -4 \text{ V}$                                                           | $I_C = -2 \text{ A}$                         | (see Notes 5 and 6)        |                    |     | -2.8           | V    |
| $V_{EC}$      | Parallel diode forward voltage       | $I_E = -5 \text{ A}$                                                              | $I_B = 0$                                    | (see Notes 5 and 6)        |                    |     | -3.5           | V    |

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

### resistive-load-switching characteristics at 25°C case temperature

| PARAMETER |               | TEST CONDITIONS <sup>†</sup> |                             |                                        | MIN | TYP | MAX | UNIT          |
|-----------|---------------|------------------------------|-----------------------------|----------------------------------------|-----|-----|-----|---------------|
| $t_{on}$  | Turn-on time  | $I_C = -2 \text{ A}$         | $I_{B(on)} = -8 \text{ mA}$ | $I_{B(off)} = 8 \text{ mA}$            |     | 2.6 |     | $\mu\text{s}$ |
| $t_{off}$ | Turn-off time | $V_{BE(off)} = 5 \text{ V}$  | $R_L = 15 \Omega$           | $t_p = 20 \mu\text{s}$ , dc $\leq 2\%$ |     | 4.5 |     | $\mu\text{s}$ |

<sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

## TYPICAL CHARACTERISTICS

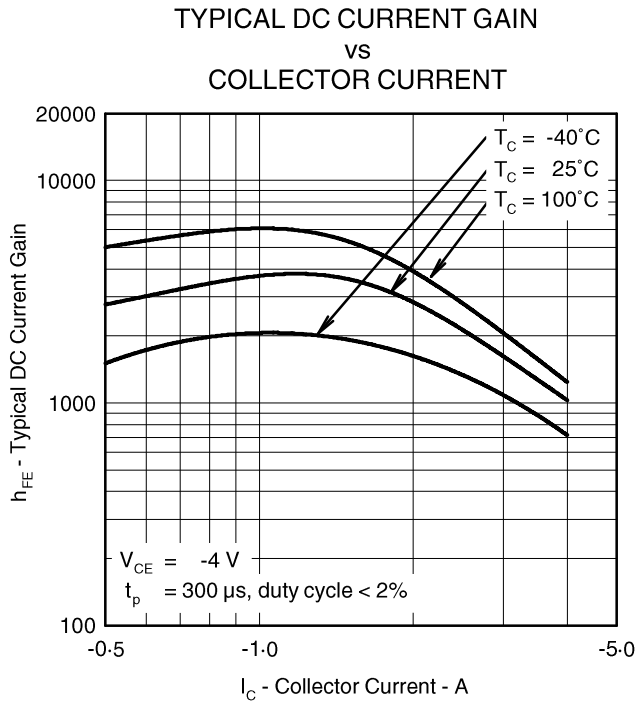


Figure 1.

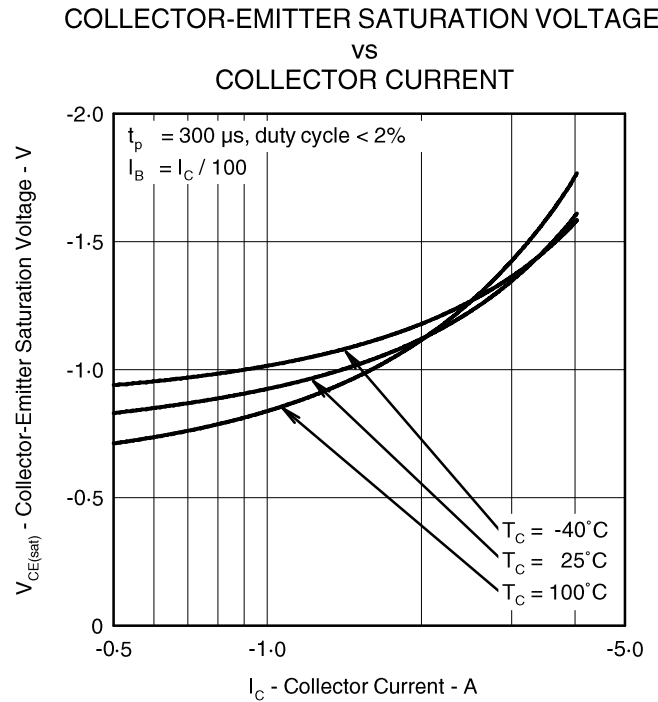


Figure 2.

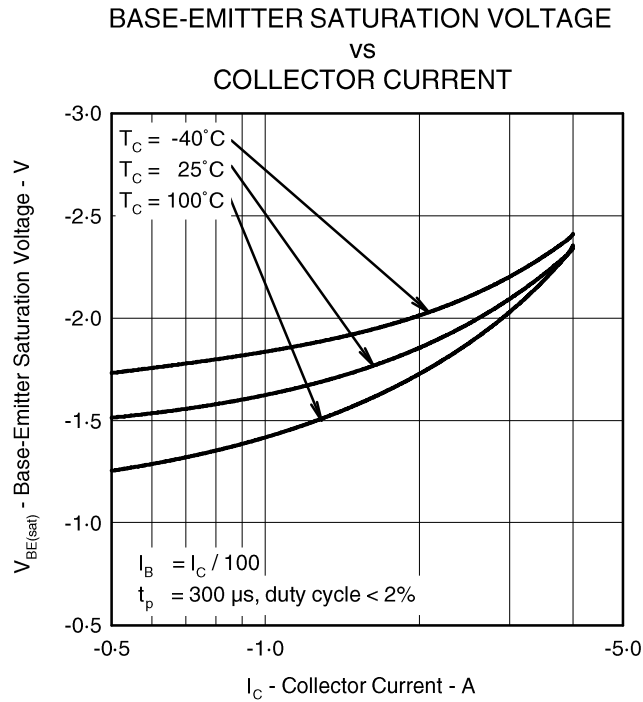


Figure 3.

MAXIMUM SAFE OPERATING REGIONS

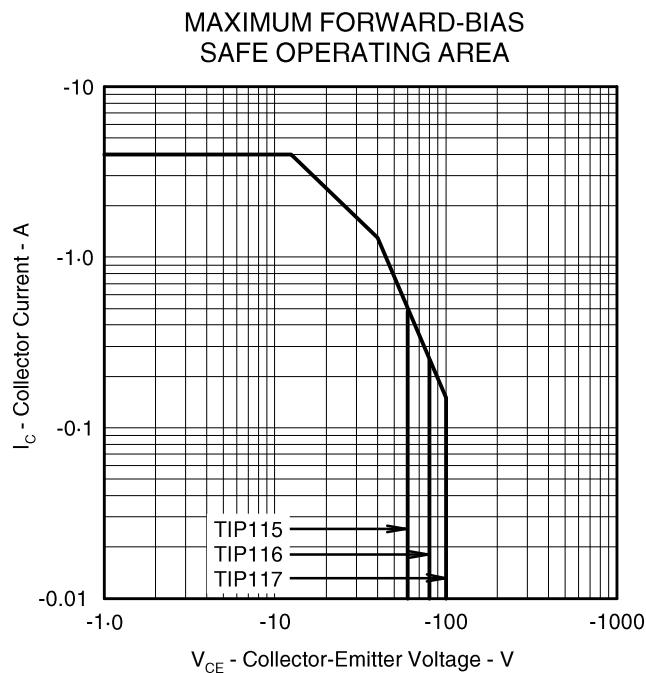


Figure 4.

THERMAL INFORMATION

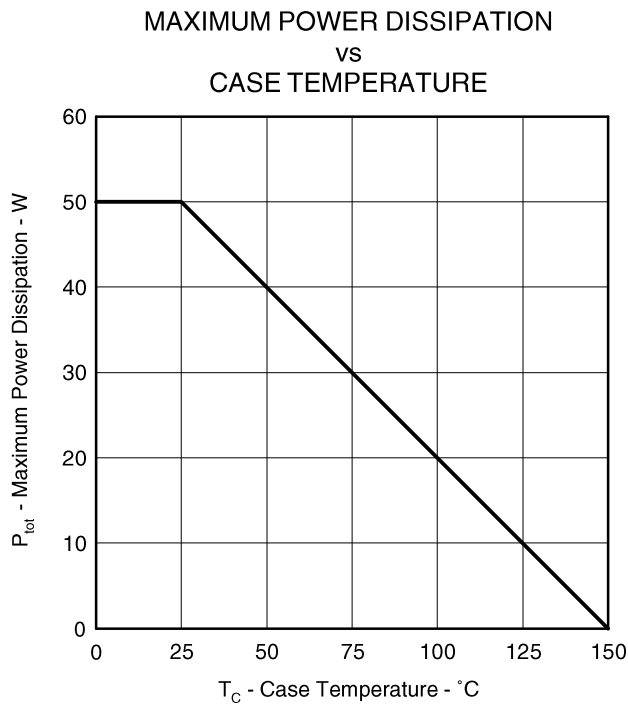


Figure 5.

# TIP115, TIP116, TIP117 PNP SILICON POWER DARLINGTONS

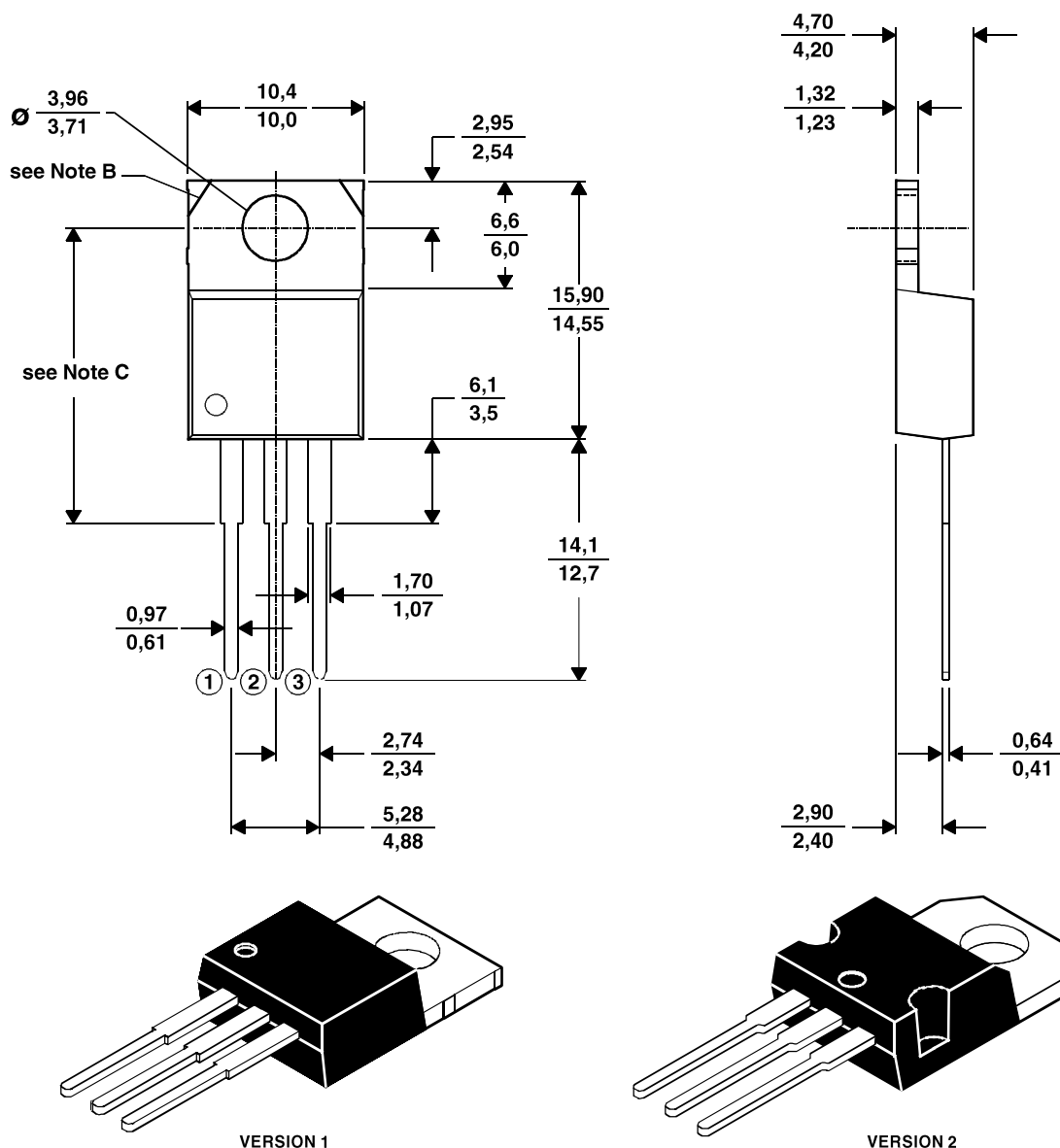
## MECHANICAL DATA

### TO-220

#### 3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.

TO220



ALL LINEAR DIMENSIONS IN MILLIMETERS

- NOTES: A. The centre pin is in electrical contact with the mounting tab.  
 B. Mounting tab corner profile according to package version.  
 C. Typical fixing hole centre stand off height according to package version.  
 Version 1, 18.0 mm. Version 2, 17.6 mm.